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User Guide for

FEBFAN7631_L17U120A

120 W LED Driver at Universal Line

Featured Fairchild Products:

FSL117MRIN

FL7930C

FAN7631

FAN73402

Direct questions or comments about this evaluation board to: "Worldwide Direct Support"

Fairchild Semiconductor.com

Table of Contents

This user guide supports the evaluation kit for the FSL117MRIN, FL7930C, FAN7631, and FAN73402; orderable as FEB-L017U120B. It should be used in conjunction with the product datasheets as well as Fairchild's application notes and technical support team. Please visit Fairchild's website at www.fairchildsemi.com.

1. Introduction

This document describes a proposed solution for a 120 W LED driver consisting of an AC-DC converter for flyback bias regulation, a boost converter for Power-Factor-Correction (PFC), an LLC resonant converter for a single LED channel with constant current and voltage or individual boost converters for two LED channels with constant current and dimming control. The input voltage range is 85 V_{RMS} – 300 V_{RMS} and there are DC outputs with a constant current of 2.4 A at 50 V_{MAX} for a single LED channel or with constant current and dimming of 1.2 V at 100 V for two LED channels.

The power supply mainly utilizes:

- FSL117MRIN – Green Mode Fairchild Power Switch (FPS™)
- FL7930B – CRM PFC Controller
- FAN7631 – Half-Bridge LLC Controller
- FAN73402 – Single-Channel Boost Controller (for each controller)
- FCPF190N60E and FCPF600N60Z – Fairchild SuperFET® Technology
- FDPF14N30 – Fairchild UniFET® Technology N-Channel MOSFET
- FFPF08H60S – Fairchild Hyperfast Rectifier
- MBR20200CT – Fairchild Schottky Rectifier
- RURD620CCS9A – Fairchild Ultra-Fast Recovery Rectifier (for discrete)

This document contains important information (e.g. schematic, bill of materials, printed circuit board layout, transformer design documentation), and the typical operating characteristics supporting this evaluation board.

1.1. General Description of FSL117MRIN

The FSL117MRIN is an integrated Pulse Width Modulation (PWM) controller and 700 V SenseFET specifically designed for offline Switched-Mode Power Supplies (SMPS) with minimal external components. The PWM controller includes an integrated fixed-frequency oscillator, Line Over-Voltage Protection (LOVP), Under-Voltage Lockout (UVLO), Leading-Edge Blanking (LEB), optimized gate driver, internal soft-start, temperature-compensated precise current sources for loop compensation, and self-protection circuitry. Compared with a discrete MOSFET and PWM controller solution, the FSL117MRIN can reduce total cost, component count, size, and weight; while simultaneously increasing efficiency, productivity, and system reliability. This device provides a basic platform for cost-effective design of a flyback converter.

1.1.1. Features

- Advanced Soft Burst Mode for Low Standby Power and Low Audible Noise
- Random Frequency Fluctuation (RFF) for Low Electromagnetic Interference (EMI)
- Pulse-by-Pulse Current Limit
- Overload Protection (OLP), Over-Voltage Protection (OVP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) with Hysteresis, Output-Short Protection (OSP), Line Over-Voltage Protection (LOVP), and Under-Voltage Lockout (UVLO) with Hysteresis
- Low Operating Current (0.4 mA) in Burst Mode
- Internal Startup Circuit
- Internal Avalanche-Rugged 700 V SenseFET
- Built-in Soft-Start: 15 ms
- Auto-Restart Mode

1.1.2. Internal Block Diagram

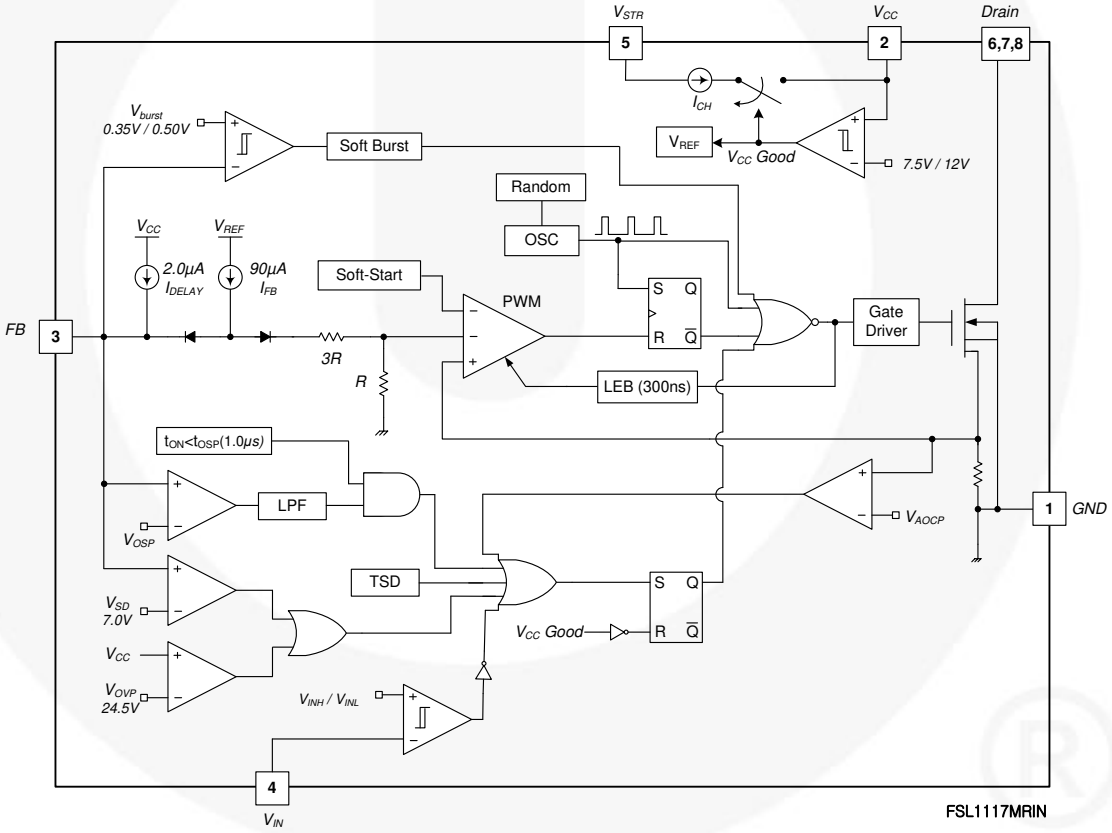

Figure 1. Block Diagram of FSL117MRIN

1.2. General Description of FL7930C

The FL7930C is an active Power Factor Correction (PFC) controller for low- to high-power lumens applications that operate in Critical Conduction Mode (CRM). It uses a voltage-mode PWM that compares an internal ramp signal with the error amplifier output to generate a MOSFET turn-off signal. Because the voltage-mode CRM PFC controller does not need rectified AC line voltage information, it saves the power loss of an input voltage-sensing network. FL7930B provides over-voltage, open-feedback, over-current, input-voltage-absent detection, and under-voltage lockout protections. The FL7930B can be disabled if the INV pin voltage is lower than 0.45 V and the operating current decreases to a very low level. Using a new variable on-time control method, Total Harmonic Discharge (THD) is lower than conventional CRM boost PFC ICs. The FL7930C provides a PFC Ready pin that can be used to shutdown the boost power stage when PFC output voltage reaches the proper level (with hysteresis).

1.2.1. Features

- Additional PFC-Ready Function
- Input-Voltage-Absent-Detection Circuit
- Maximum Switching Frequency Limitation.
- Internal Soft-Start with Overshoot Prevention
- Internal Total harmonic Distortion (THD) Optimizer
- Precise Adjustable Output Over-Voltage Protection (OVP)
- Open-Feedback Protection and Disable Function
- Zero Current Detector (ZDC)
- 150 μs Internal Startup Timer
- MOSFET Over-Current Protection (OCP)
- Under-Voltage Lockout with 3.5 V Hysteresis (UVLO)
- Low Startup (40 μA) and Operating Current (1.5 mA)
- Totem-Pole Output with High State Clamp
- +500 / -800 mA Peak Gate Drive Current
- SOP-8 Package

1.2.2. Internal Block Diagram

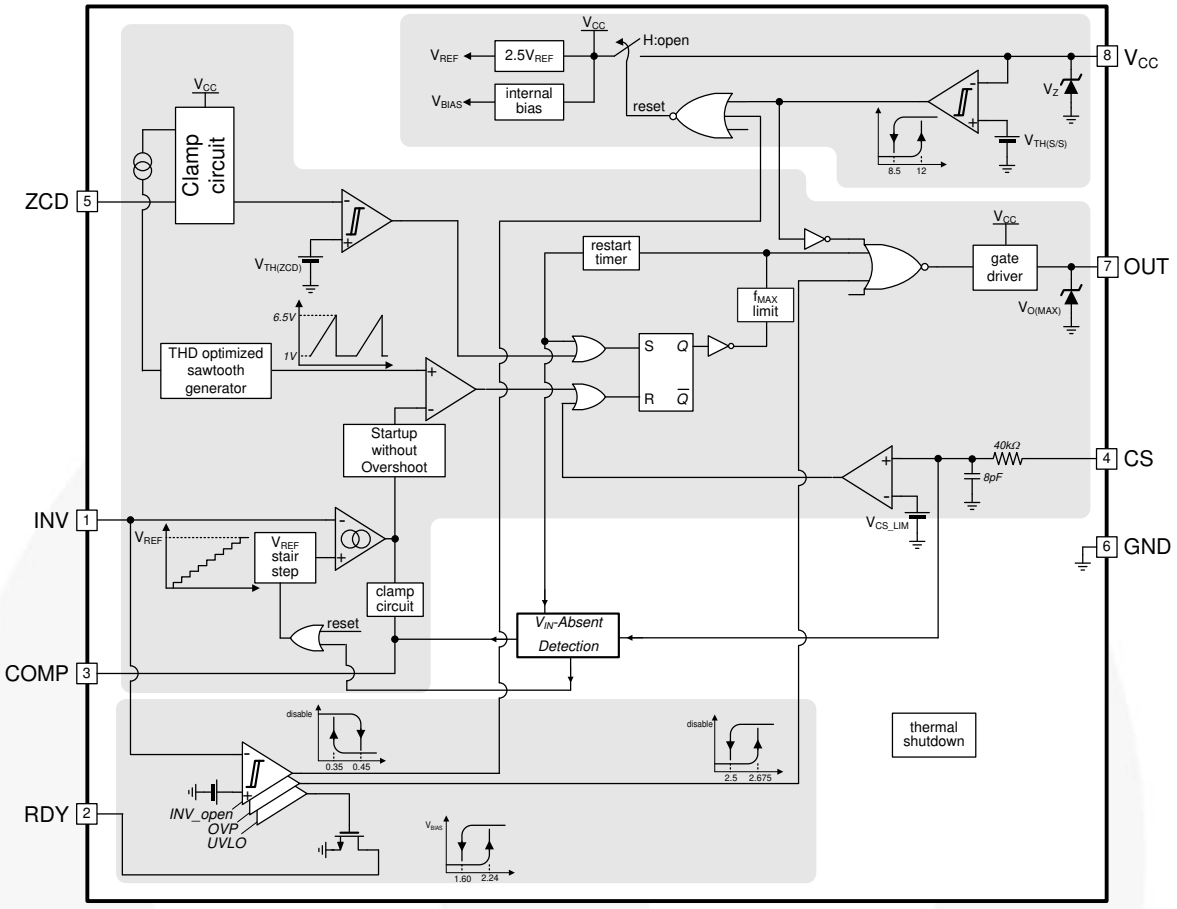

Figure 2. Block Diagram of FL7930C

1.3. General Description of FAN7631

The FAN7631 is a pulse-frequency modulation controller for high-efficiency half-bridge resonant converters that includes a high-side gate drive circuit, an accurate current-controlled oscillator, and various protection functions. The FAN7631 features include variable dead time, high operating frequency up to 600 kHz, protections such as LUVLO, and a selectable latch or A/R protection using the LS pin for user convenience. The Zero-Voltage-Switching (ZVS) technique reduces the switching losses and improves the efficiency significantly. ZVS also reduces the switching noise noticeably, which allows a small Electromagnetic Interference (EMI) filter. Offering everything necessary to build a reliable and robust resonant converter, the FAN7631 simplifies designs and improves productivity and performance. The FAN7631 can be applied to resonant converter topologies such as series resonant, parallel resonant, and LLC resonant converters.

1.3.1. Features

- Variable Frequency Control with 50% Duty Cycle for Half-bridge Resonant Converter Topologies
- High Efficiency through Zero-Voltage-Switching (ZVS)
- Up to 600 kHz Operating Frequency
- High Gate-Driving Current +500 mA/-1000 mA
- Precise Adjustable Output Over-Voltage Protection (OVP)
- Programmable Dead Time using a Resistor
- Pulse Skipping and Burst Operation for Frequency Limit (programmable) at Light-Load Condition
- Simple Remote on/off Control with Selectable Latch or A/R using FI or LS pin
- Protection Function; Over-Voltage Protection (OVP), Overload Protection (OLP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD) and High Precise Line Under-Voltage Lockout (LUVLO)
- Level-Change OCP Function during Startup.
- SOP-16 Package

1.3.2. Internal Block Diagram

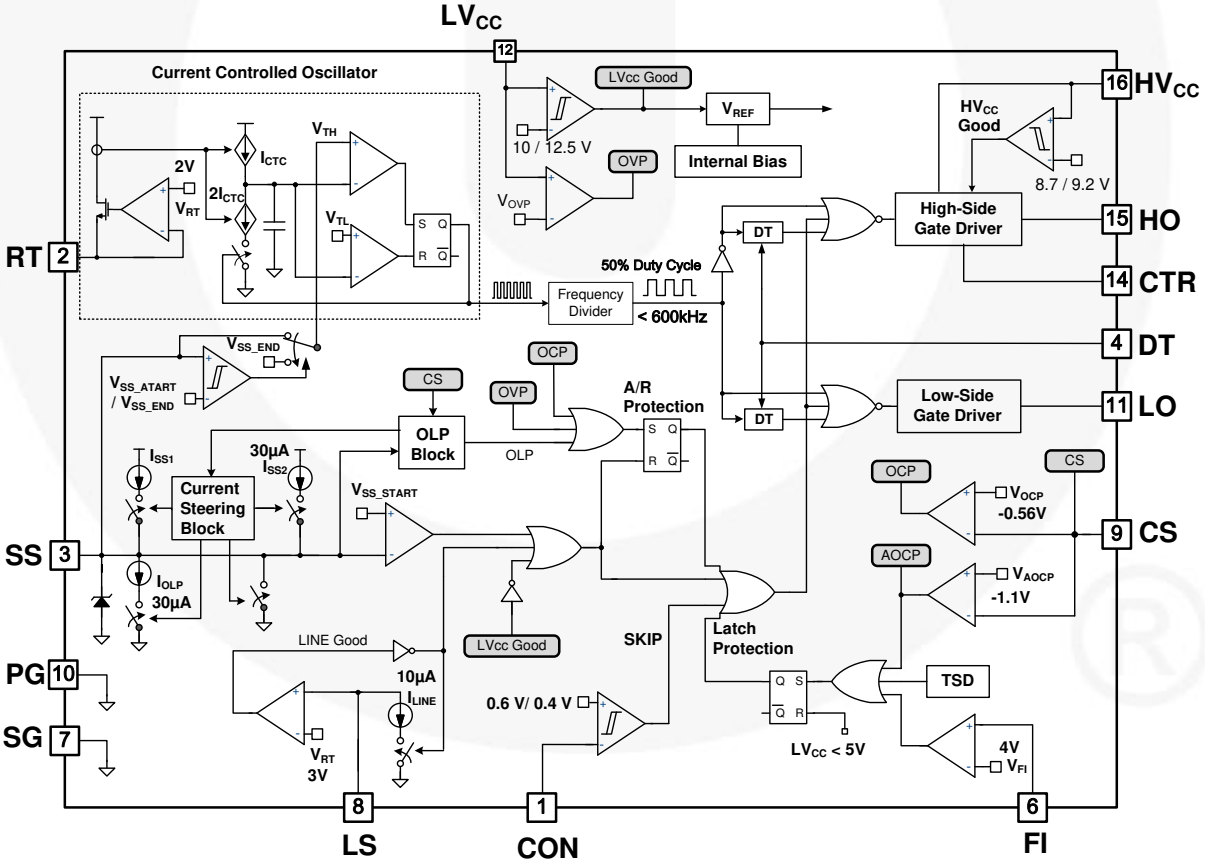

Figure 3. Block Diagram of FAN7631

1.4. General Description of FAN73402

The FAN73402 is a single-channel boost controller that integrates an N-channel power MOSFET for PWM dimming using Fairchild's proprietary planar Double-diffused MOSFET (DMOS) technology. The IC operates as a constant-current source for driving high-current LEDs. It uses Current Mode control with programmable slope compensation to prevent sub-harmonic oscillation. The IC provides protections including: open-LED protection, over-voltage protection, and direct-short protection for high system reliability. The IC internally generates a FAULT signal with delay if an abnormal LED string condition occurs. PWM dimming and analog dimming functions can be implemented independently. Internal soft-start prevents inrush current flowing into output capacitor at startup.

1.4.1. Features

- Single-Channel Boost LED Switch
- Internal Power MOSFET for PWM Dimming: $R_{DS(ON)}$=1.0 Ω at V_{GS}=10 V, BV_{DSS}=200 V
- Current-Mode PWM Control
- Internal Programmable Slope Compensation
- Wide Supply Voltage Range: 10 V to 35 V
- LED Current Regulation: ±1%
- Programmable Switching Frequency
- Analog and PWM Dimming
- Wide Dimming Ratio: On Time=10 µs to DC
- Cycle-by-Cycle Current Limiting
- Thermal Shutdown: 150°C
- Open-LED Protection (OLP)
- Over-Voltage Protection (OVP)
- Over-Current Protection (OCP)
- Error Flag Generation (for External Load Switch)
- Internal Soft-Start
- 16-Lead SOIC Package

1.4.2. Internal Block Diagram

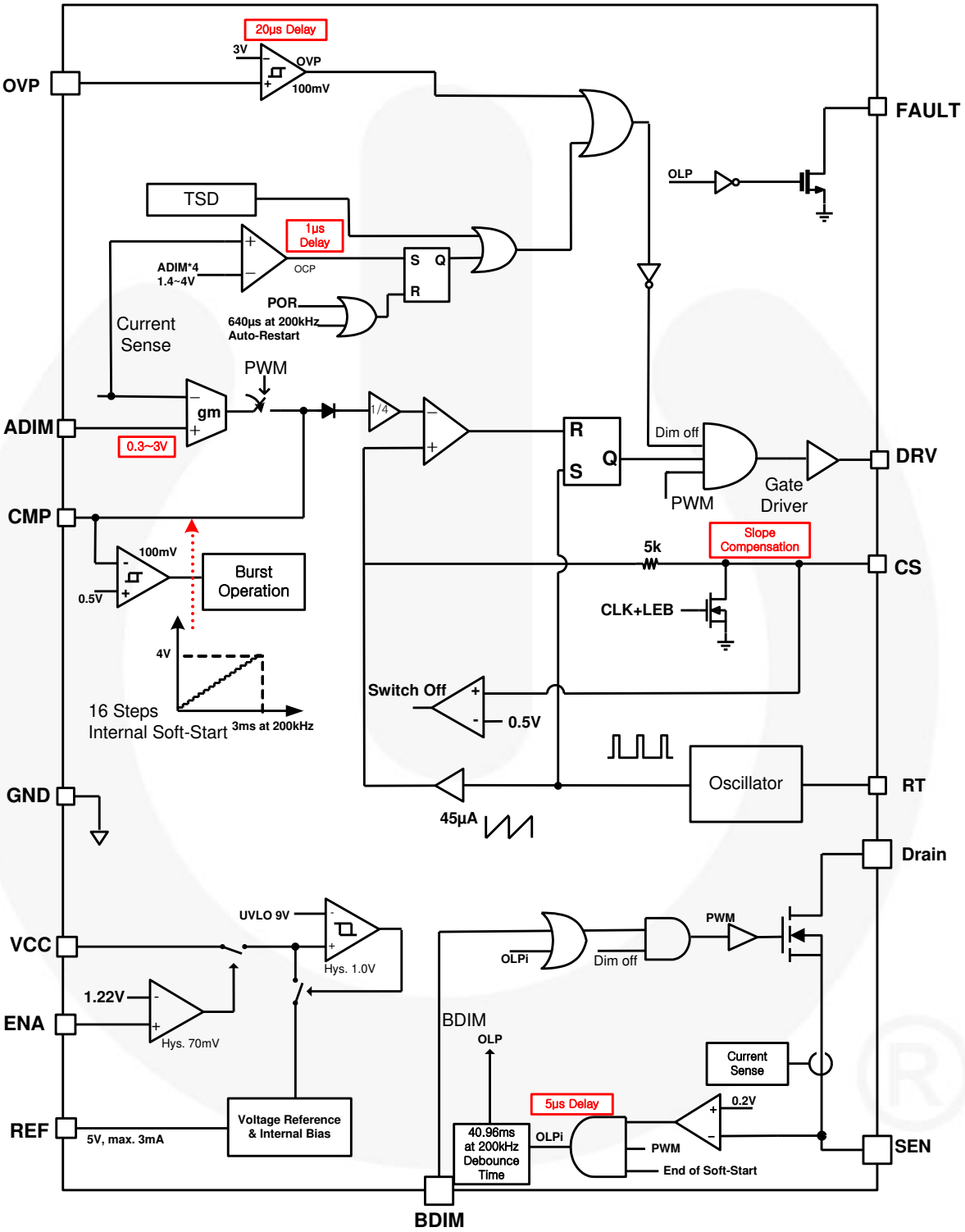

Figure 4. Block Diagram of FAN73402

2. Specifications for Evaluation Board

Table 1. Specifications for LED Lighting Lamp

Description		Symbol	Value	Comments
Input	Voltage	$V_{IN.MIN}$	85 V_{AC}	Minimum Input Voltage
		$V_{IN.MAX}$	300 V_{AC}	Maximum Input Voltage
		$V_{IN.NOMINAL}$	120 V/230 V	Nominal Input Voltage
	Frequency	f_{IN}	60 Hz/50 Hz	Line Frequency
Output	Voltage	V_{OUT_SINGLE}	50 V	Output Voltage for Single Channel LED
		$V_{OUT\_MULTI.}$	100 V	Output Voltage for Multi Channel LED
	Current	I_{OUT_SINGLE}	2.4 A	Output Current for Single Channel LED
		$I_{OUT\_MULTI.}$	1.2 A	Output Current for Multi Channel LED
Efficiency [Single Channel]		Eff_{85VAC}	87.77%	Efficiency at 85 V_{AC} Line Input Voltage
		Eff_{120VAC}	90.06%	Efficiency at 120 V_{AC} Line Input Voltage
		Eff_{140VAC}	90.86%	Efficiency at 140 V_{AC} Line Input Voltage
		Eff_{180VAC}	91.55%	Efficiency at 180 V_{AC} Line Input Voltage
		Eff_{230VAC}	91.99%	Efficiency at 230 V_{AC} Line Input Voltage
		Eff_{300VAC}	92.33%	Efficiency at 300 V_{AC} Line Input Voltage
Standby Power		P_{85VAC}	0.283 W	Standby Power at 85 V_{AC} Line Input Voltage
		P_{120VAC}	0.306 W	Standby Power at 120 V_{AC} Line Input Voltage
		P_{140VAC}	0.315 W	Standby Power at 140 V_{AC} Line Input Voltage
		P_{180VAC}	0.319 W	Standby Power at 180 V_{AC} Line Input Voltage
		P_{230VAC}	0.341 W	Standby Power at 230 V_{AC} Line Input Voltage
		P_{300VAC}	0.397 W	Standby Power at 300 V_{AC} Line Input Voltage
PF/THD		PF/THD_{85VAC}	0.998/4.58%	PF/THD at 85 V_{AC} Line Input Voltage
		PF/THD_{120VAC}	0.997/4.65%	PF/THD at 120 V_{AC} Line Input Voltage
		PF/THD_{140VAC}	0.995/4.74%	PF/THD at 140 V_{AC} Line Input Voltage
		PF/THD_{180VAC}	0.992/5.32%	PF/THD at 180 V_{AC} Line Input Voltage
		PF/THD_{230VAC}	0.980/7.89%	PF/THD at 230 V_{AC} Line Input Voltage
		PF/THD_{300VAC}	0.945/15.13%	PF/THD at 300 V_{AC} Line Input Voltage
Temperature	FSL117MRIN	$T_{FSL117MRIN}$	53.9°C	FSL117MRIN Temperature at 25°C
	FAN73402	$T_{FAN73402}$	82.1°C	FAN73402 Temperature at 25°C
	MOSFET	T_{PFC}	63.0°C	PFC MOSFET Temperature at 25°C
		T_{LLC}	59.2°C	LLC MOSFET Temperature at 25°C
		$T_{Boost\_Channel}$	61,8°C	Boost Channel MOSFET Temperature at 25°C
		T_{LLC}	67.5°C	LLC Rectifier Temperature at 25°C
		$T_{Boost\_Channel}$	69.5°C	Boost Channel Rectifier Temperature at 25°C
		$T_{\_LLC}$	72.6°C	LLC Transformer Temperature at 25°C

All data of the evaluation board measured with the board enclosed in a case and external temperature around 25°C.

3. Photographs

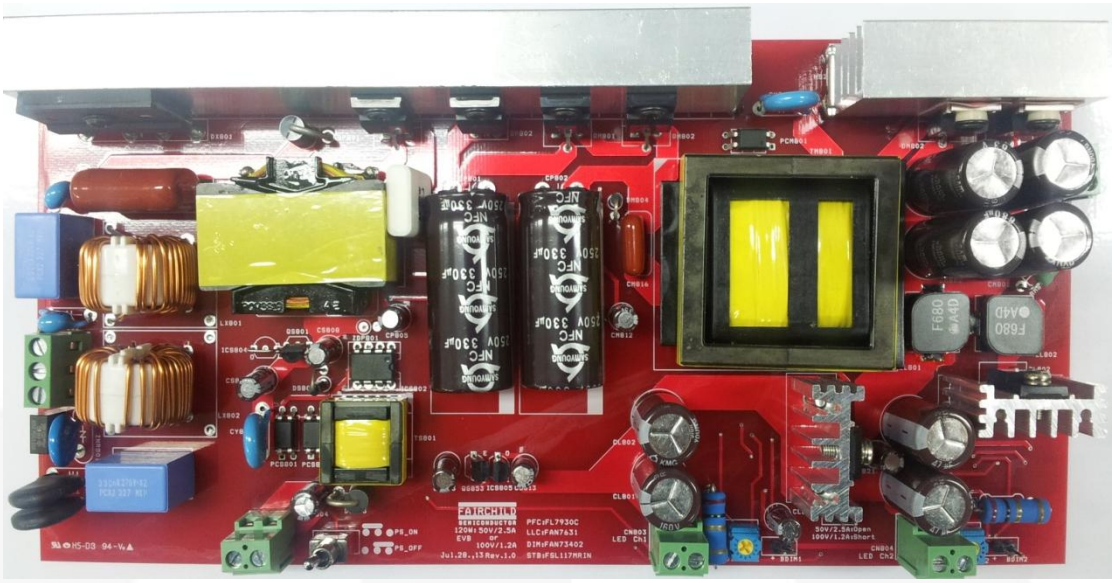

Figure 5. Top View [Dimensions: 232mm (L) x 114 mm (W) x 27 mm (H)]

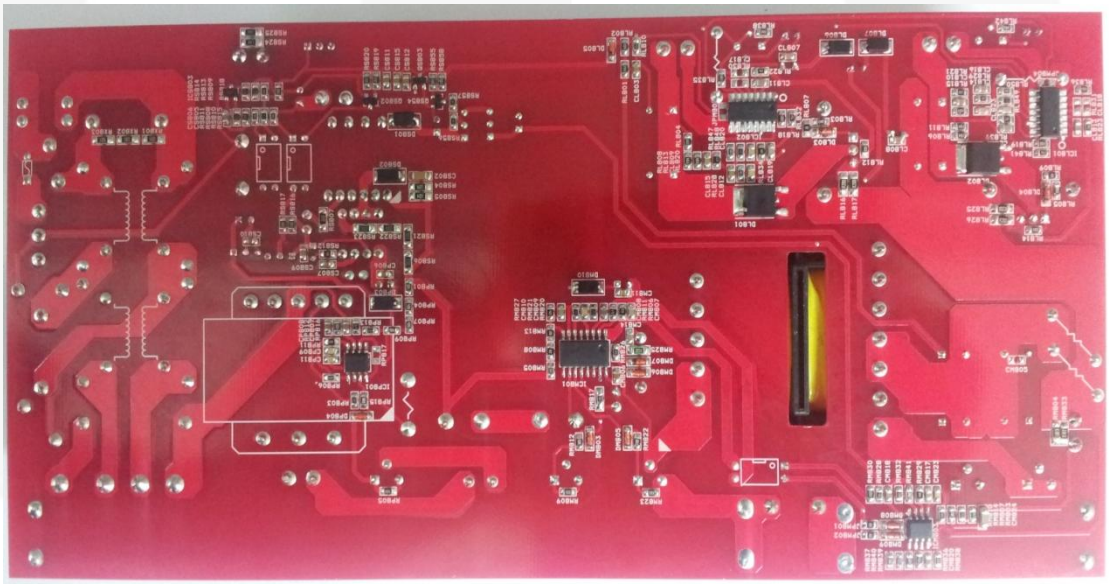

Figure 6. Bottom View [Dimensions: 232mm (L) x 114 mm (W) x 27 mm (H)]

4. Printed Circuit Board (PCB)

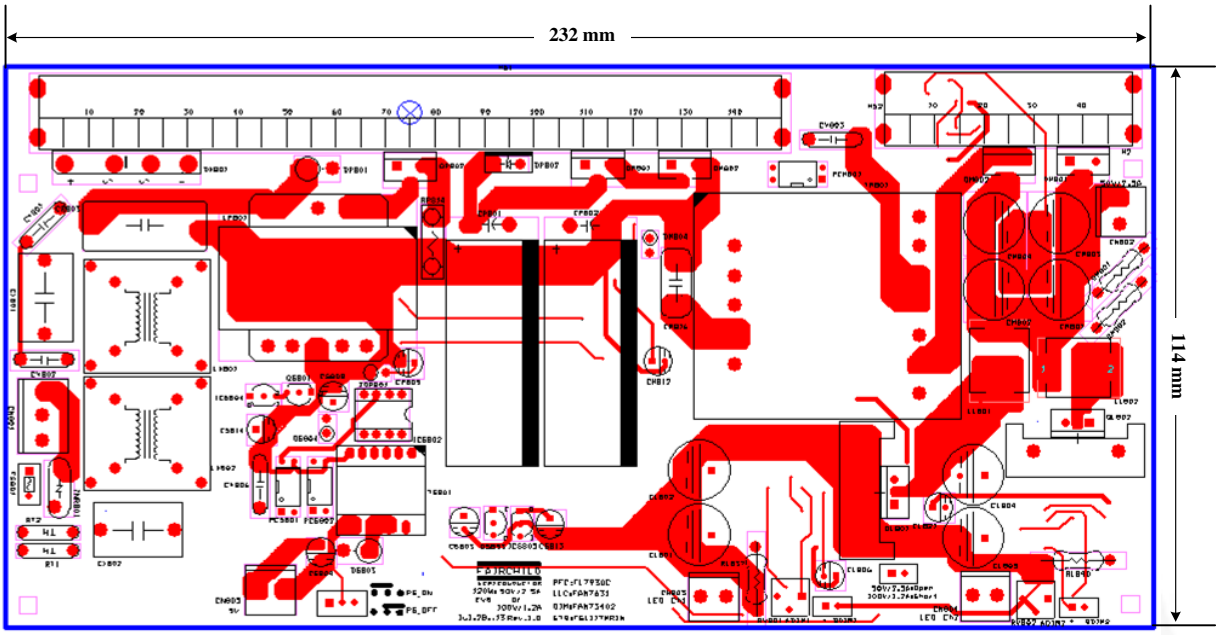

Figure 7. Top Pattern

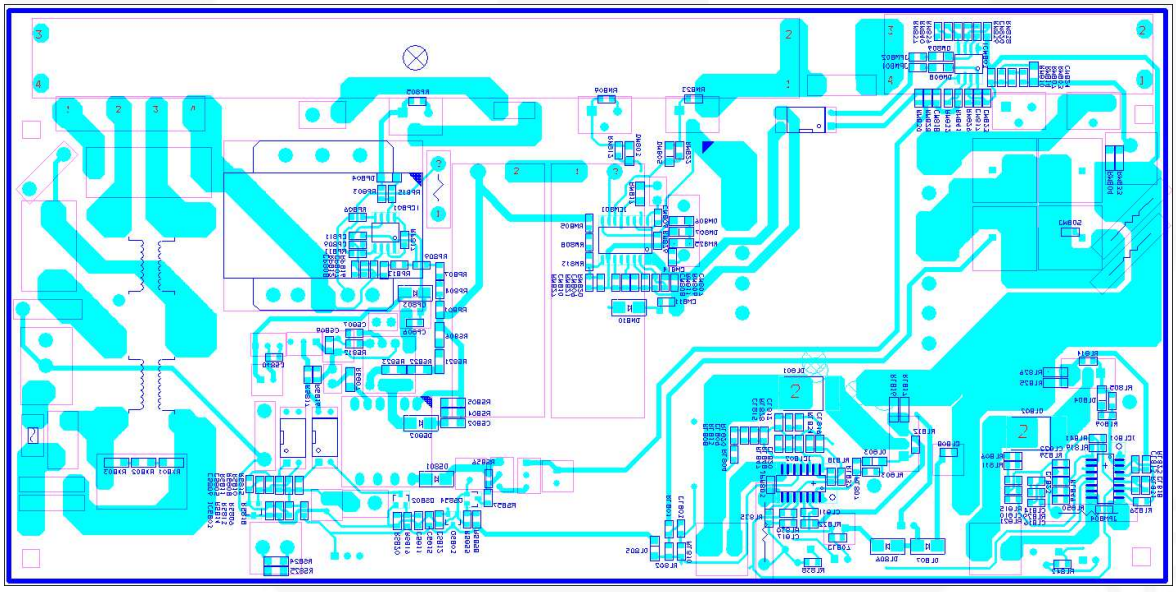

Figure 8. Bottom Pattern

5. Schematic

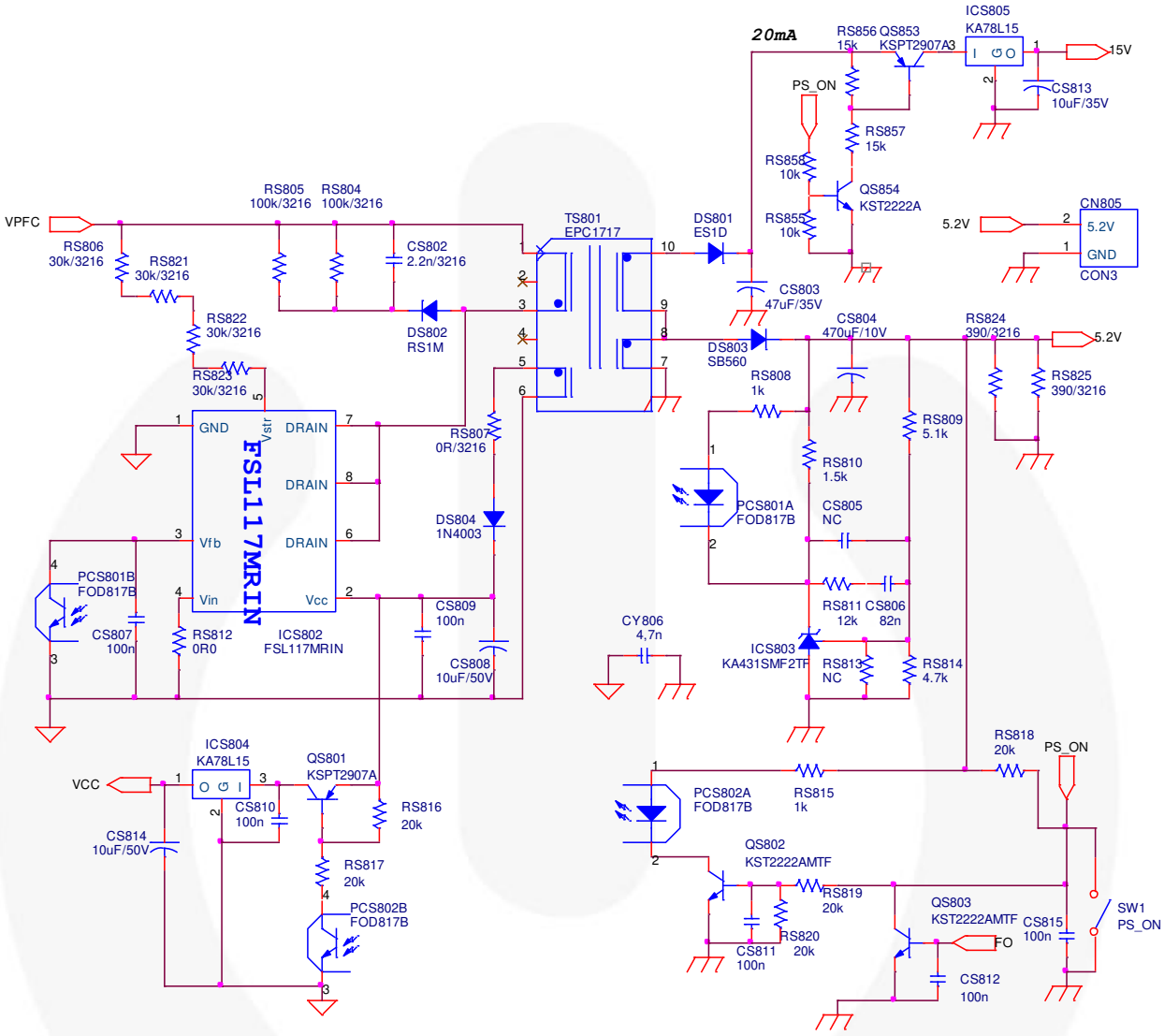

Figure 9. Schematic for Flyback Bias Regulator Part

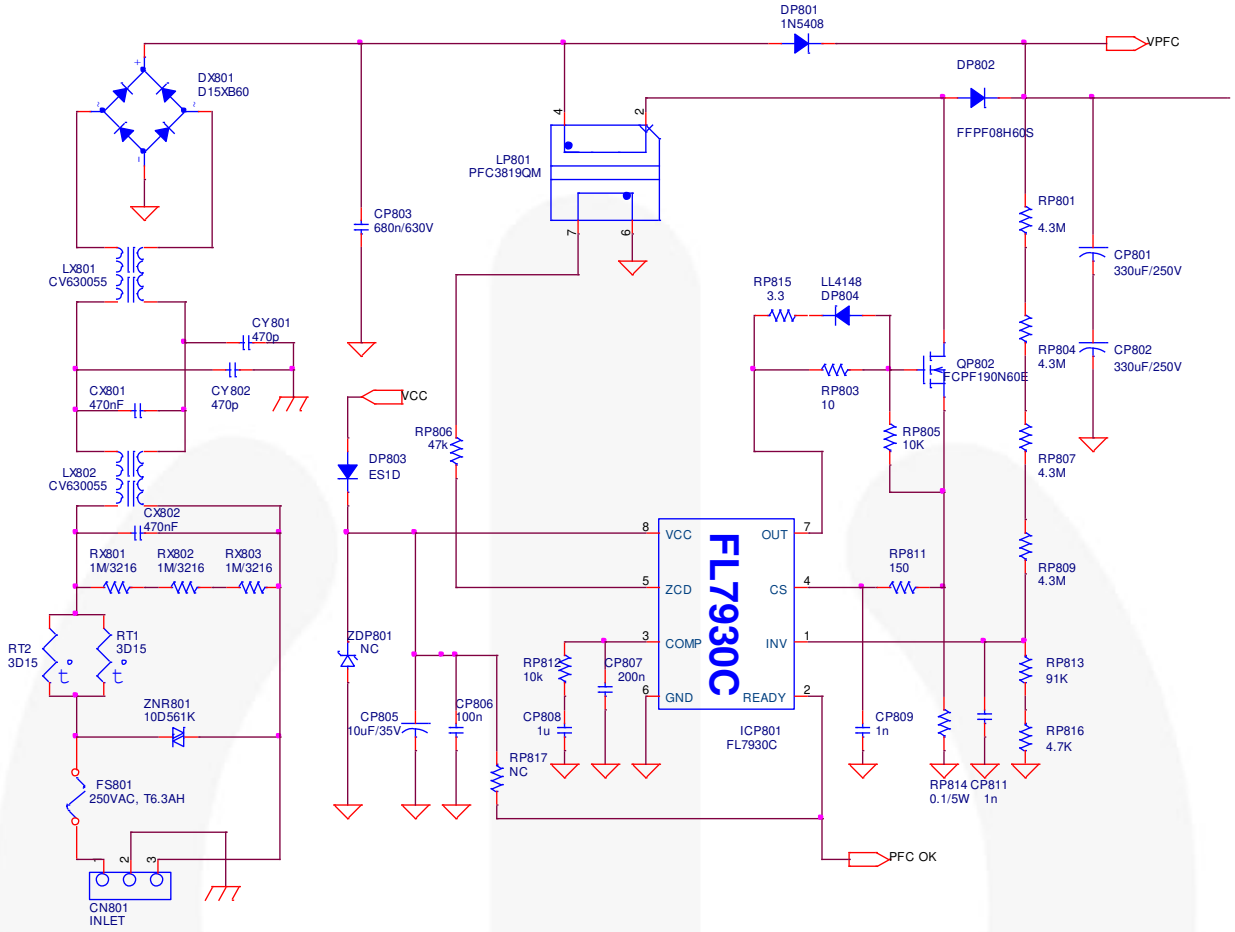

Figure 10. Schematic for PFC Part

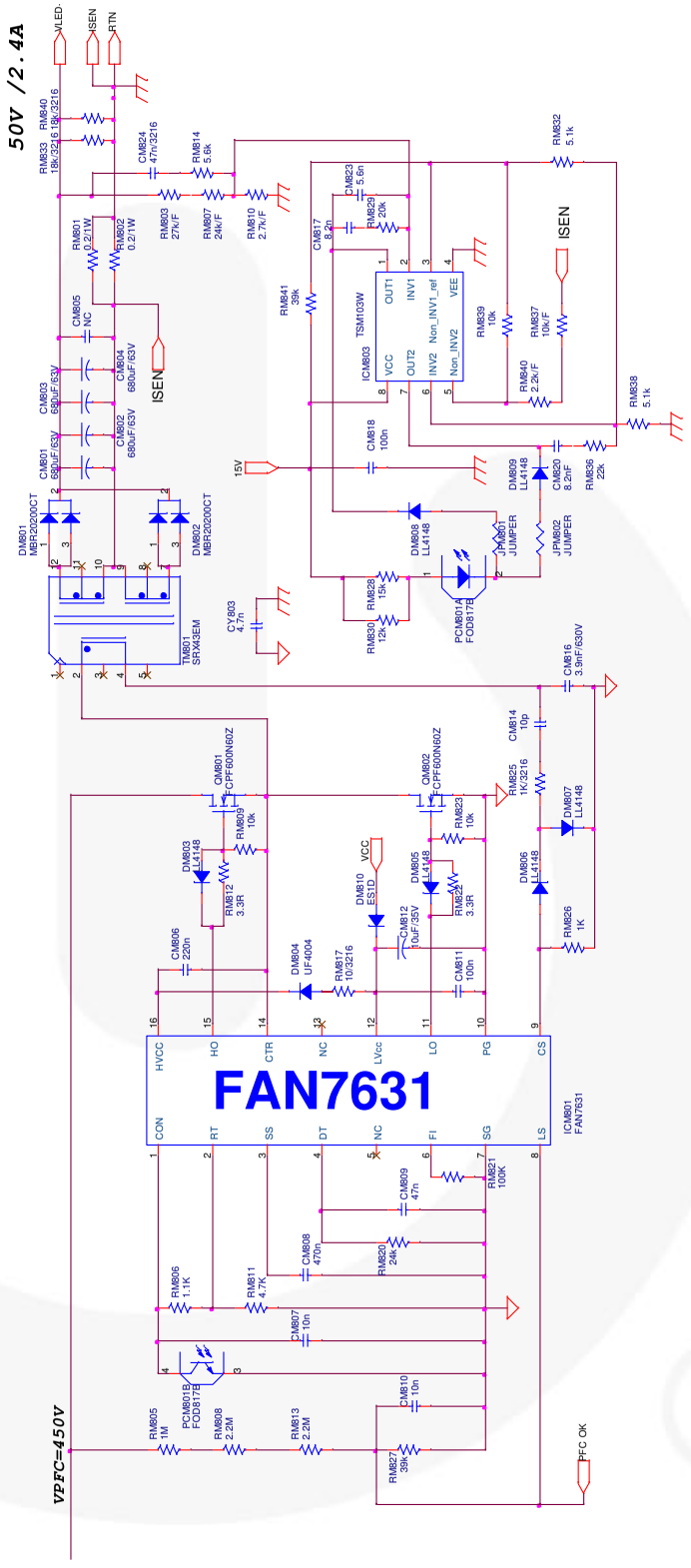

Figure 11. Schematic for LLC Part

※RM830 should be NC in case of 50 V/2.4 A output and use 16 k value in case of 100 V/1.2 A output.

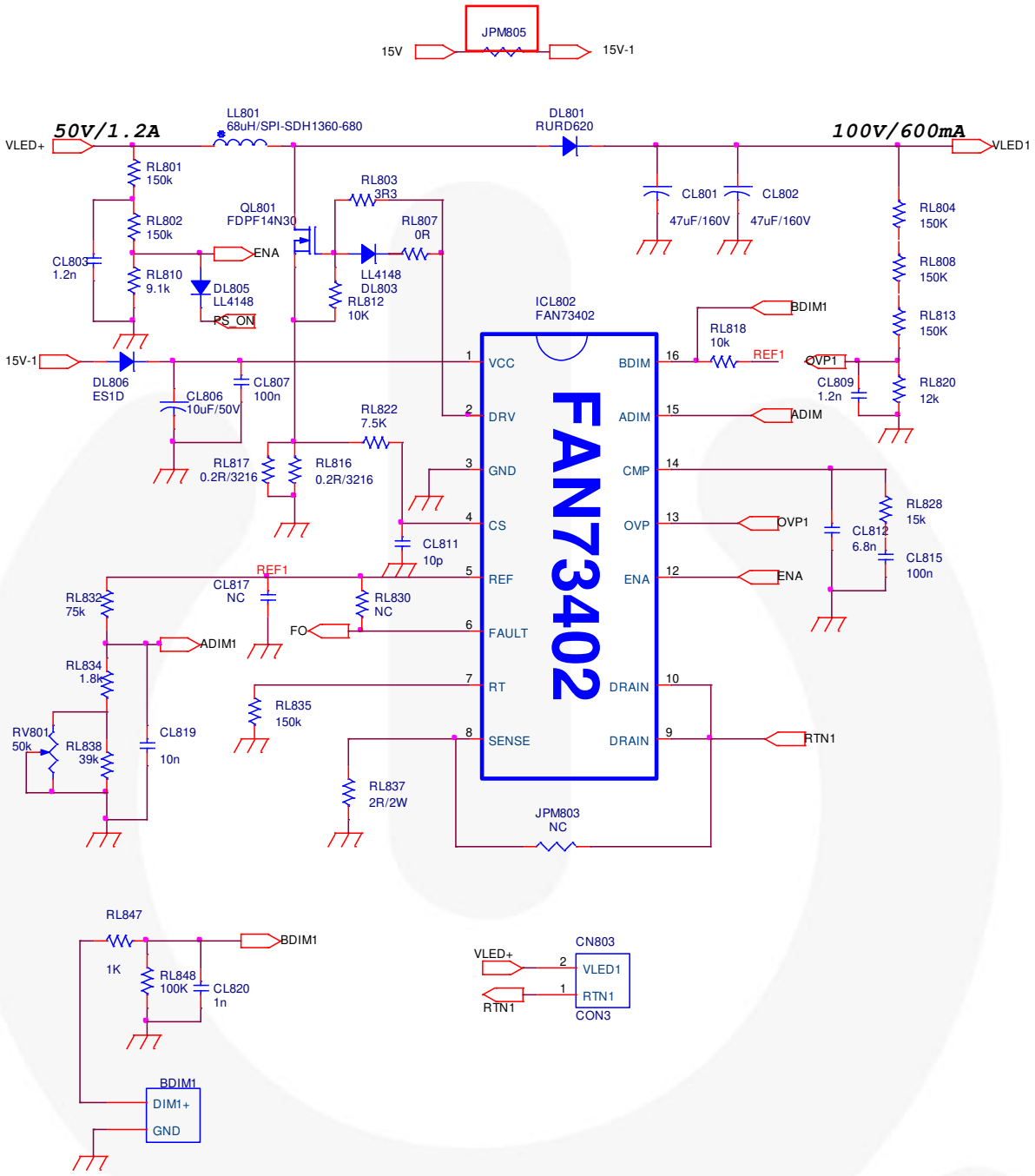

Figure 12. Schematic for Boost Channel 1.

※JPM805 should be opened in case of 50 V/2.4 A output and shorted in case of 100 V/1.2 A output.

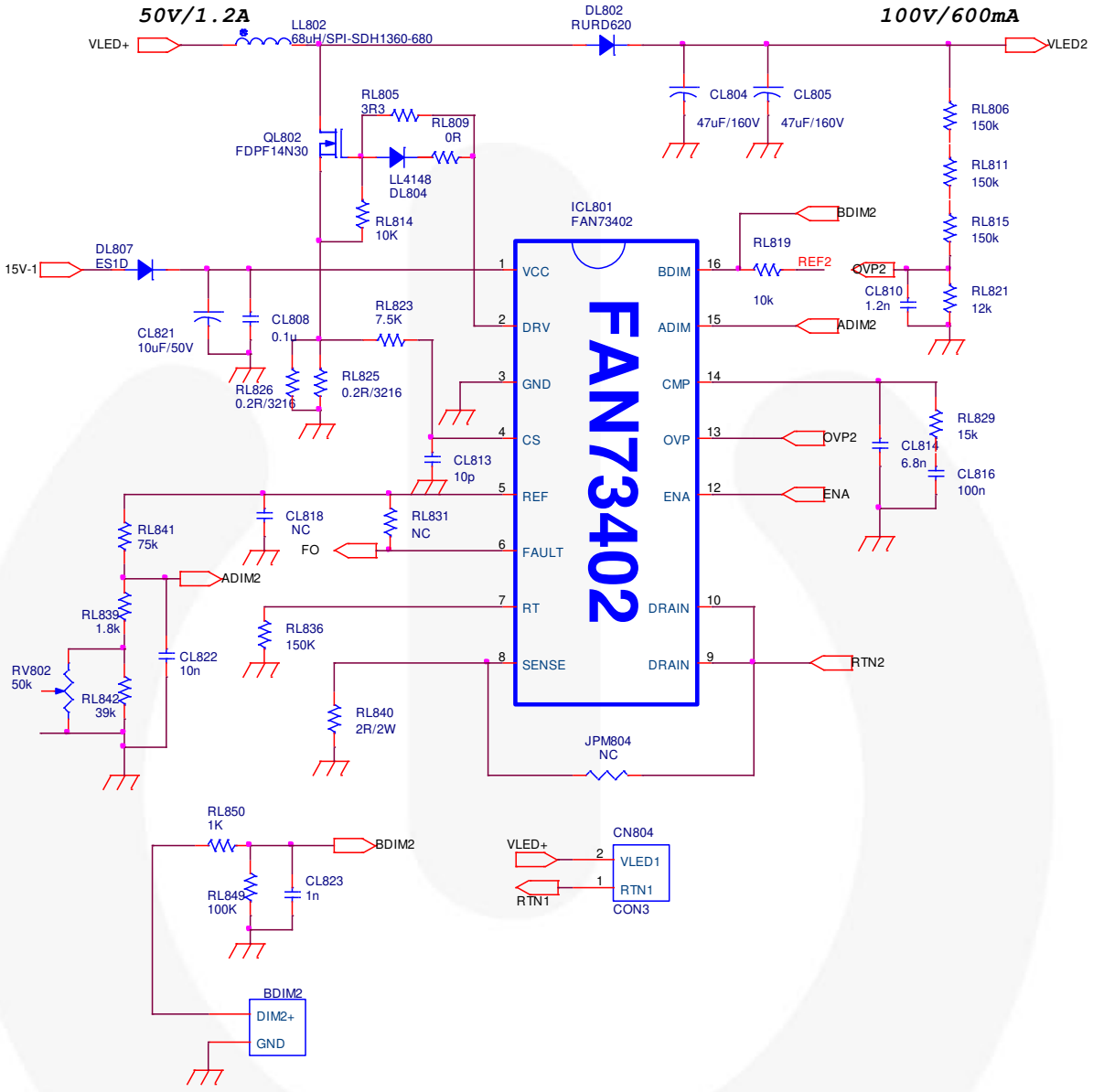

Figure 13. Schematic for Boost Channel 2

6. Bill of Materials

No.	Part Reference	Part Value	Qty.	Description	Vendor
1	BDIM1, BDIM2	2 Pin	1	2 Pin Connector	Molex
2	CL801, CL802, CL804, CL805	47 µF/160 V	4	Electrolytic Capacitor	Samyoung
3	CL803, CL809, CL810	C0805C112J5GACTU	3	1.2 nF/50 V, SMD MLCC	Kemet
4	CL806, CS808, CS814, CL821	KMG 10 µF/35 V	4	Electrolytic Capacitor	Samyoung
5	CP806, CS807, CL807, CS809, CS810, CS811, CM811, CS812, CS815, CL815, CL816, CM818, CL808	C0805C104J5GACTU	13	1.2 nF/50 V, SMD MLCC	Kemet
6	CL811, CL813, CM814	C0805C100J5GACTU	3	10 pF/50 V, SMD MLCC	Kemet
7	CL812, CL814	C0805C683J5GACTU	2	6.8 nF/50 V, SMD MLCC	Kemet
8	CM807, CM810, CL819, CL822	C0805C103J5GACTU	4	10 nF/50 V, SMD MLCC	Kemet
9	CP809,CP811,CL820,CL823	C0805C102J5GACTU	4	1 nF/50 V, SMD MLCC	Kemet
10	CM801, CM802, CM803, CM804	NHL 330 µF/250V	4	Electrolytic Capacitor	Samyoung
11	CM806	C0805C224J5GACTU	1	220 nF/50 V, SMD MLCC	Kemet
12	CM808	C0805C474J5GACTU	1	470 nF/50 V, SMD MLCC	Kemet
13	CM809	C0805C473J5GACTU	1	47 nF/50 V, SMD MLCC	Kemet
14	CM816	4.7 nF/630 V	1	Film Capacitor	Sungho
15	CM817, CM820	C0805C822J5GACTU	2	8.2 nF/50 V, SMD MLCC	Kemet
16	CM823	C0805C562J5GACTU	1	5.6 nF/50 V, SMD MLCC	Kemet
17	CM824	C1206C473J1GACTU	1	47 nF/100 V, SMD MLCC	Kemet
18	CN801	3 Pin	1	3 Pin Connector	Molex
19	CN802, CN803, CN804, CN805	2 Pin	4	2 Pin Connector	Molex
20	CP801, CP802	KMG 330 µF/250 V	2	Electrolytic Capacitor	Samyoung
21	CP803	680 n/630 V	1	Film Capacitor	Sungho
22	CP805, CM812, CS813	KMG 10 µF/35 V	3	Electrolytic Capacitor	Samyoung
23	CP807	C0805C204J5GACTU	1	200 nF/50 V, SMD MLCC	Kemet
24	CP808	C0805C105J5GACTU	1	1 µF/50 V, SMD MLCC	Kemet
25	CS802	C1206C202J5GACTU	1	2.2 nF/630 V, SMD MLCC	Kemet
26	CS803	KMG 47 µF/35 V	1	Electrolytic Capacitor	Samyoung
27	CS804	KMG 470 µF/35 V	1	Electrolytic Capacitor	Samyoung

No.	Part Reference	Part Value	Qty.	Description	Vendor
28	CS806	C1206C823J5GACTU	1	82 nF/50 V, SMD MLCC	Kemet
29	CX801, CX802	MPX334	2	X-Capacitor	Carli
30	CY801, CY802	SDC471J10FS10	2	Y-Capacitor	Samwha
31	CY803, CY806	SDC472J10FK7	1	Y-Capacitor	Samwha
32	DL801, DL802	RURD620	2	200 V/6 A Ultrafast Diode	Fairchild Semiconductor
33	DM803, DL803, DP804, DL804, DM805, DL805, DM806, DM807, DM808, DM809	LL4148	10	Small Signal Diode	Fairchild Semiconductor
34	DS801, DP803, DL806, DL807, DM810	ES1D	5	200 V/1 A, Ultra-Fast Diode	Fairchild Semiconductor
35	DM801, DM802	MBR20200CT	2	200 V/20 A, Schottky Rectifier	Fairchild Semiconductor
36	DM804	UF4004	1	400 V/1.0 A, Ultra-Fast Diode	Fairchild Semiconductor
37	DP801	1N5408	1	1000 V/3 A, General Rectifier	Fairchild Semiconductor
38	DP802	FFPF08H60S	1	8 A, 600 V, Hyper-Fast Diode	Fairchild Semiconductor
39	DS802	RS1M	1	1000 V/1 A, Ultra-Fast Diode	Fairchild Semiconductor
40	DS803	SB560	1	60 V/5 A, Schottky Rectifier	Fairchild Semiconductor
41	DS804	1N4003	1	Ultra-Fast Diode	Fairchild Semiconductor
42	DX801	D15XB60	1	600 V 15 A, Bridge Diode	Shindengen
43	FS801	SS-5-3.15 A	1	250 V/3.15 A, Fuse	Bussmann
44	HS1	150 mm	1	Heat Sink [Primary]	
45	HS2	50 mm	1	Heat Sink [Secondary]	
46	ICL801, ICL802	FAN73402	2	LED Boost Switch	Fairchild Semiconductor
47	ICM801	FAN7631	1	LLC Controller	Fairchild Semiconductor
48	ICM803	TSM103W	1	Dual OP-Amp	ST
49	ICP801	FL7930C	1	PFC Controller	Fairchild Semiconductor
50	ICS802	FSL117MRIN	1	Green Mode FPS	Fairchild Semiconductor
51	ICS803	KA431SMF2TF	1	Shunt Regulator	Fairchild Semiconductor
52	ICS804, ICS805	KA78L15	2	15 V Voltage Regulator	Fairchild Semiconductor
53	JPM805	JUMPER	1	Jumper	Molex
54	LL801, LL802	68 µH/SPI-SDH1360-680	2	68 µH, SMD Inductor	TDK

No.	Part Reference	Part Value	Qty.	Description	Vendor
55	LP801	PFC3819QM	1	300 µH, PFC Inductor	TDK
56	LX801, LX802	CV630055	2	Line Filter	TNC
57	PCM801, PCS801, PCS802	FOD817B	3	Opto-Coupler	Fairchild Semiconductor
58	QL801, QL802	FDPF14N30	2	300 V/14 A MOSFET	Fairchild Semiconductor
59	QM801, QM802	FCPF600N60Z	2	600 V/R_{DSON}:0.19 Ω, MOSFET	Fairchild Semiconductor
60	QP802	FCPF190N60E	1	600 V/R_{DSON}:0.6 Ω, MOSFET	Fairchild Semiconductor
61	QS801, QS853	KSPT2907A	2	PNP Transistor	Fairchild Semiconductor
62	QS802, QS803, QS854	KST2222AMTF	3	NPN Transistor	Fairchild Semiconductor
63	RL801, RL802, RL804, RL806, RL808, RL811, RL815, RL835, RL836, RL813	RC0805JR-07150KL	10	150 kΩ, 2012 SMD	Yageo
64	RL803, RL805	RC0805JR-073R3L	2	3.3 Ω, 2012 SMD	Yageo
65	RL807, RL809, JPM801, JPM802, RS812	RC0805JR-070RL	5	0 Ω, 2012 SMD	Yageo
66	RL810	RC0805JR-079k1L	1	9.1 kΩ, 2012 SMD	Yageo
67	RP805, RM809, RP812, RL812, RL814, RL818, RL819, RM823, RM839, RS855, RS858	RC0805JR-0710kL	11	10 kΩ, 2012 SMD	Yageo
68	RL816, RL817, RL825, RL826	RC1206JR-070R2L	4	0.2 Ω, 3216 SMD	Yageo
69	RS811, RL820, RL821, RM830	RC0805JR-0712kL	4	12 kΩ, 2012 SMD	Yageo
70	RL822 RL823	RC0805JR-077k5L	2	7.5 kΩ, 2012 SMD	Yageo
71	RM828, RL828, RL829, RS856, RS857	RC0805JR-0715kL	5	15 kΩ, 2012 SMD	Yageo
72	RL832, RL841	RC0805JR-0775kL	2	75 kΩ, 2012 SMD	Yageo
73	RL834, RL839	RC0805JR-071k8L	2	1.8 kΩ, 2012 SMD	Yageo
74	RL837, RL840	2 Ω/2 W	2	2 Ω, 2 W Resistor	Abel
75	RM827, RL838, RM841, RL842	RC0805JR-0739kL	4	39 kΩ, 2012 SMD	Yageo
76	RS808, RS815, RM826, RL847, RL850	RC0805JR-071kL	5	1 kΩ, 2012 SMD	Yageo
77	RM821, RL848, RL849	RC0805JR-07100kL	3	100 kΩ, 2012 SMD	Yageo
78	RM801, RM802	0.2 Ω/1 W	2	0.2 Ω, 1 W Resistor	Abel
79	RM803	RC0805FR-0727kL	1	27 kΩ/F, 2012 SMD	Yageo
80	RM805	RC0805JR-071ML	1	1 MΩ, 2012 SMD	Yageo
81	RM806	RC0805JR-071k1L	1	1.1 kΩ, 2012 SMD	Yageo
82	RM807	RC0805FR-0724kL	1	24 kΩ/F, 2012 SMD	Yageo
83	RM808, RM813	RC0805JR-072M2L	2	2.2MΩ, 2012 SMD	Yageo
84	RM810	RC0805FR-072k7L	1	2.7 kΩ/F, 2012 SMD	Yageo
85	RM811, RS814	RC0805JR-074k7L	2	4.7 kΩ, 2012 SMD	Yageo
86	RM812, RM822, RP815	RC0805JR-073R3L	3	3.3 Ω, 2012 SMD	Yageo
87	RM814	RC0805JR-075k6L	1	5.6 kΩ, 2012 SMD	Yageo

No.	Part Reference	Part Value	Qty.	Description	Vendor
88	RM817	RC1206JR-0710RL	1	10 Ω, 2012 SMD	Yageo
89	RM820	RC0805JR-0724kL	1	24 kΩ, 2012 SMD	Yageo
90	RM825	RC1206JR-071KL	1	1 kΩ, 3216 SMD	Yageo
91	RS816, RS817, RS818, RS819, RS820, RM829	RC0805JR-0720kL	6	20 kΩ, 2012 SMD	Yageo
92	RS809, RM832, RM838	RC0805JR-075k1L	3	5.1 kΩ, 2012 SMD	Yageo
93	RM833, RM840	RC1206JR-0718KL	2	18 kΩ, 2012 SMD	Yageo
94	RM836	RC0805JR-072k2L	1	2.2 kΩ, 2012 SMD	Yageo
95	RM837	RC0805FR-0710kL	1	10 kΩ/F, 2012 SMD	Yageo
96	RM840	RC0805FR-072k2L	1	2.2 kΩ/F, 2012 SMD	Yageo
97	RP801, RP804, RP807, RP809	RC0805JR-074M3L	4	4.3 MΩ, 2012 SMD	Yageo
98	RP803	RC0805JR-0710RL	1	10 Ω, 2012 SMD	Yageo
99	RP806	RC0805JR-0747KL	1	47 kΩ, 2012 SMD	Yageo
100	RP811	RC0805JR-07150L	1	150 Ω, 2012 SMD	Yageo
101	RP813	RC0805JR-0791KL	1	91 kΩ, 2012 SMD	Yageo
102	RP814	0.1 Ω/5 W	1	0.1 Ω, 5 W Resistor	Abel
103	RP816	RC0805JR-074K7L	1	4.7 kΩ, 2012 SMD	Yageo
104	RS804, RS805	RC1206JR-07100KL	2	100 kΩ, 3216 SMD	Yageo
105	RS806, RS821, RS822, RS823	RC1206JR-0730KL	4	30 kΩ, 3216 SMD	Yageo
106	RS807	RC1206JR-070RL	1	0 Ω, 3216 SMD	Yageo
107	RS810	RC0805JR-071k5L	1	1.5 kΩ, 2012 SMD	Yageo
108	RS824, RS835	RC1206JR-07120L	1	390 Ω, 3216 SMD	Yageo
109	RT1, RT2	3D15	2	NTC Thermistor	Daekwang S
110	RV801, RV802	50 kΩ/0.5 W	2	50 kΩ, Variable Resistor	Vishay
111	RX801, RX802, RX803	RC1206JR-071ML	3	1 MΩ, 3216 SMD	Yageo
112	SW1	Toggle Switch	1	3 Terminal Switch	Phonix
113	TM801	SRX43EM	1	LLC Transformer	TDK
114	TS801	EPC1717	1	LLC Transformer	TDK
115	ZNR801	10D561K	1	MOV	Samwha
116	CL817, CL818, CM805, CS805	NC	4		
117	RS813, RP817, JPM803, JPM804, RL830, RL831	NC	6		
118	ZDP801	NC	1		

7. Transformer Design

7.1. Flyback Transformer (TS801)

- Core: EPC1717 (TDK)
- Bobbin: 10 Pin

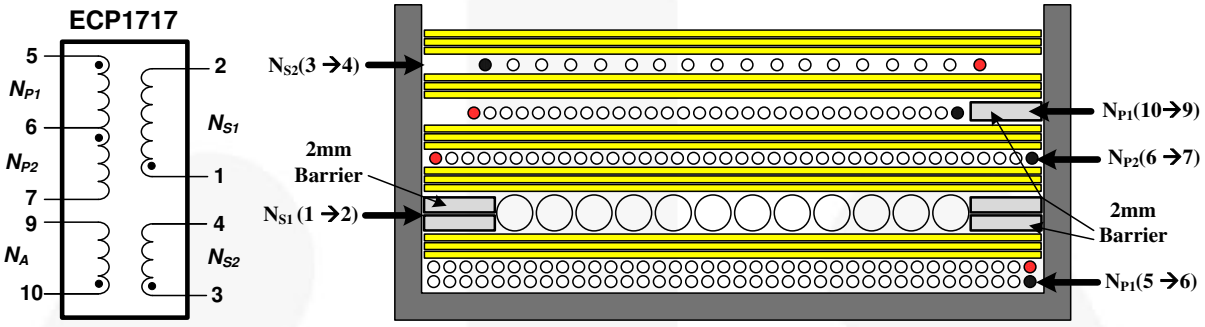

Figure 14. Transformer Pin Assignment and Configuration

Table 2. Winding Specifications

No.	Winding	Pin (S → F)	Wire	Turns	Winding Method
1	N_{P1}	5 → 6	0.15φ	100 Ts	Solenoid Winding
2	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
3	N_{S1}	1 → 2	0.45φ	12 Ts	Solenoid Winding
4	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
5	N_{P2}	6 → 7	0.25φ	44 Ts	Solenoid Winding
6	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
7	N_A	10 → 9	0.15φ	37 Ts	Solenoid Winding
8	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
9	N_{S2}	3 → 4	0.25φ	22 Ts	Solenoid Winding
10	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				

Table 3. Electrical Characteristics

	Pin	Specifications	Remark
Inductance [Lp]	5 – 7	900 µH ±10%	60 kHz, 1 V
Leakage [Ll]	5 – 7	55 µH	60 kHz, 1 V at Short All Output Pins

7.2. PFC Inductor (LP801)

- Core: PFC3819QM(TDK)
- Bobbin: PQM3819, 8 Pin

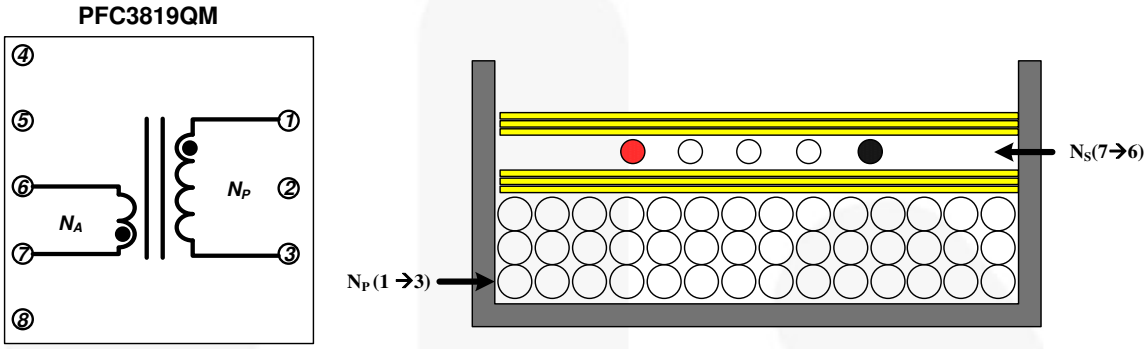

Figure 15. Transformer Pin Assignment and Configuration

Table 4. Winding Specifications

No.	Winding	Pin (S → F)	Wire	Turns	Winding Method
1	N_P	1 → 3	0.1*65[Litz]	40 Ts	Solenoid Winding
2	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
3	N_{S1}	7 → 6	0.45φ	4 Ts	Solenoid Winding
4	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				

Table 5. Electrical Characteristics

	Pin	Specifications	Remark
Inductance	1 – 3	300 µH ±10%	60 kHz, 1 V

7.3. LLC Transformer (TM801)

- Core: SRX43EM (TDK)
- Bobbin: EEX4333P12-1, 12 Pin

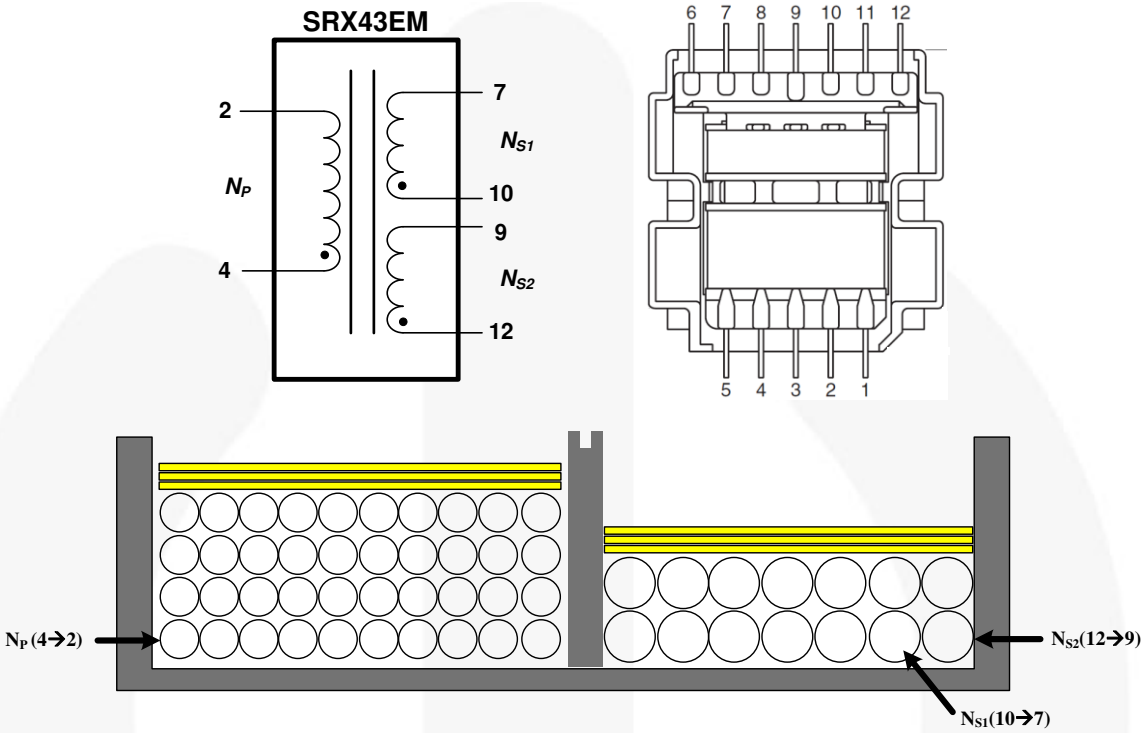

Figure 16. Transformer Pin Assignment and Configuration

Table 6. Winding Specifications

No.	Winding	Pin (S → F)	Wire	Turns	Winding Method
1	N_P	4 → 2	0.1φ * 60 [Litz]]	37 Ts	Solenoid Winding
2	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				
3	N_{S1}	12 →9	0.08 φ *120[Litz]]	7 Ts	Solenoid Winding
	N_{S2}	10 → 7		7 Ts	Solenoid Winding
4	Insulation: Polyester Tape t = 0.025 mm, 3-Layer				

Table 7. Electrical Characteristics

	Pin	Specifications	Remark
Inductance [Lp]	4 – 2	810 µH ±10%	100 kHz, 1 V
Leakage [Lr]	5 – 7	105 µH	Short One of the Secondary Windings